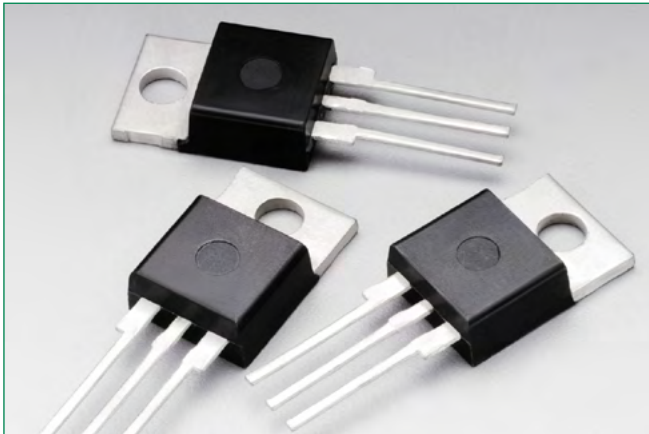


# MAC12D, MAC12M, MAC12N

Surface Mount – 400V - 800V



## Description

The MAC12x is designed for high performance full-wave AC control applications where high noise immunity and commutating di/dt are required.

## Features

- Blocking Voltage to 800 Volts
- On-State Current Rating of 12 Amperes RMS at 70°C
- Uniform Gate Trigger Currents in Three Quadrants, Q1, Q2, and Q3
- High Immunity to dv/dt – 250 V/μs Minimum at 125°C
- High Commutating di/dt – 6.5 A/ms Minimum at 125°C
- Industry Standard TO–220 Package
- High Surge Current Capability – 100 Amperes
- These Devices are Pb–Free and are RoHS Compliant

## Additional Information



Resources

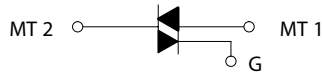


Accessories

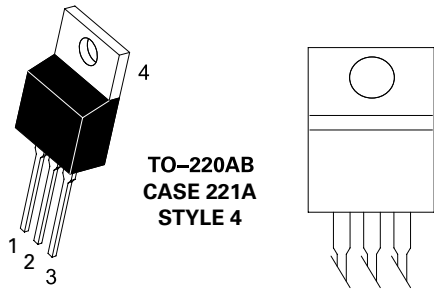


Samples

## Functional Diagram



## Pin Out



# MAC12D, MAC12M, MAC12N

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### Maximum Ratings (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit	
Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, T <sub>J</sub> = 40° to 125°C)	MAC12D MAC12M MAC12N	V <sub>DRM*</sub> V <sub>RRM</sub>	400 600 800	V
On-State RMS Current (Full Cycle Sine Wave, 60 Hz, T <sub>C</sub> = 70°C)	I <sub>T (RMS)</sub>	12	A	
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T <sub>J</sub> = 125°C)	I <sub>TSM</sub>	100	A	
Circuit Fusing Consideration (t = 8.3 ms)	I <sup>2</sup> t	41	A <sup>2</sup> sec	
Peak Gate Power (Pulse Width ≤ 1.0 μs, T <sub>C</sub> = 80°C)	P <sub>GM</sub>	16	W	
Average Gate Power (t = 8.3 ms, T <sub>C</sub> = 80°C)	P <sub>G(AV)</sub>	0.35	W	
Operating Junction Temperature Range	T <sub>J</sub>	-40 to +125	°C	
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

### Thermal Characteristics

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case (AC) Junction-to-Ambient	R <sub>θJC</sub> R <sub>θJA</sub>	2.2 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	T <sub>L</sub>	260	°C

### Electrical Characteristics - OFF (T<sub>J</sub> = 25°C unless otherwise noted ; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit
Peak Repetitive Blocking Current (V <sub>D</sub> = V <sub>DRM</sub> = V <sub>RRM</sub> ; Gate Open)	I <sub>DRM*</sub> I <sub>RRM</sub>	-	-	0.01	mA
		-	-	2.0	

### Electrical Characteristics - ON (T<sub>J</sub> = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic	Symbol	Min	Typ	Max	Unit		
Peak On-State Voltage (Note 2) (I <sub>TM</sub> = ±11 A)	V <sub>TM</sub>	-	-	1.85	V		
Gate Trigger Current (Continuous dc) (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 Ω)	MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	I <sub>GT</sub>	5.0	13	35	mA	
Holding Current (V <sub>D</sub> = 12 V, Gate Open, Initiating Current = ±150 mA)	I <sub>H</sub>	-	20	40	mA		
	Latching Current (V <sub>D</sub> = 24 V, I <sub>G</sub> = 35 mA)	MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	I <sub>L</sub>	-			20
Gate Trigger Voltage (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 Ω)	MT2(+), G(+)	V <sub>GT</sub>	0.5	0.78	1.5	V	
	MT2(+), G(-)	0.5	0.70	1.5			
	MT2(-), G(-)	0.5	0.71	1.5			

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Indicates Pulse Test: Pulse Width ≤ 2.0 ms, Duty Cycle ≤ 2%.

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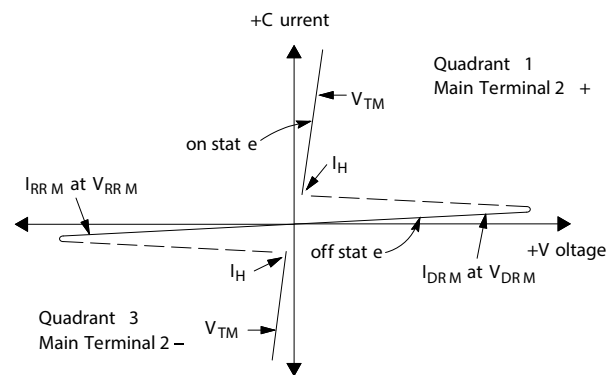
Surface Mount – 400V - 800V

## Dynamic Characteristics

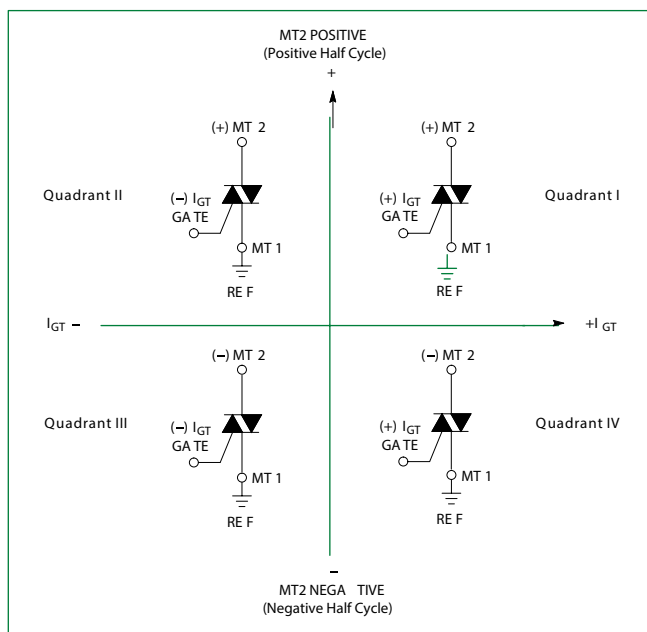
Characteristic	Symbol	Min	Typ	Max	Unit
Rate of Change of Commutating Current See Figure 10. ( $V_D = 400\text{ V}$ , $I_{TM} = 4.4\text{ A}$ , Commutating $dv/dt = 18\text{ V}/\mu\text{s}$ , Gate Open, $T_J = 125^\circ\text{C}$ , $f = 250\text{ Hz}$ , No Snubber)	$di/dt_{(C)}$	6.5	–	–	A/ms
Critical Rate of Rise of Off-State Voltage ( $V_D = \text{Rated } V_{DRM}$ , Exponential Waveform, Gate open, $T_J = 125^\circ\text{C}$ )	$dV/dt$	250	500	–	V/ $\mu\text{s}$
Repetitive Critical Rate of Rise of On-State Current IPK = 50 A; PW = 40 $\mu\text{sec}$ ; $diG/dt = 200\text{ mA}/\mu\text{sec}$ ; $f = 60\text{ Hz}$	$di/dt$	–	–	10	A/ $\mu\text{s}$

## Voltage Current Characteristic of SCR

Symbol	Parameter
$V_{DRM}$	Peak Repetitive Forward Off State Voltage
$I_{DRM}$	Peak Forward Blocking Current
$V_{RRM}$	Peak Repetitive Reverse Off State Voltage
$I_{RRM}$	Peak Reverse Blocking Current
$V_{TM}$	Maximum On State Voltage
$I_H$	Holding Current



## Quadrant Definitions for a Triac

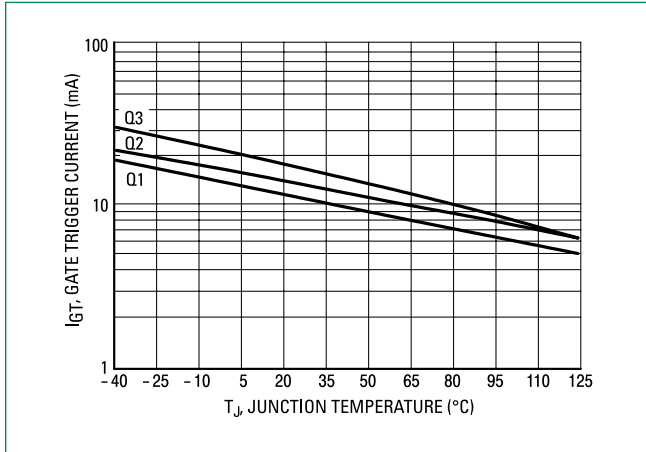


All polarities are referenced to MT1.  
With in-phase signals (using standard AC lines) quadrants I and III are used

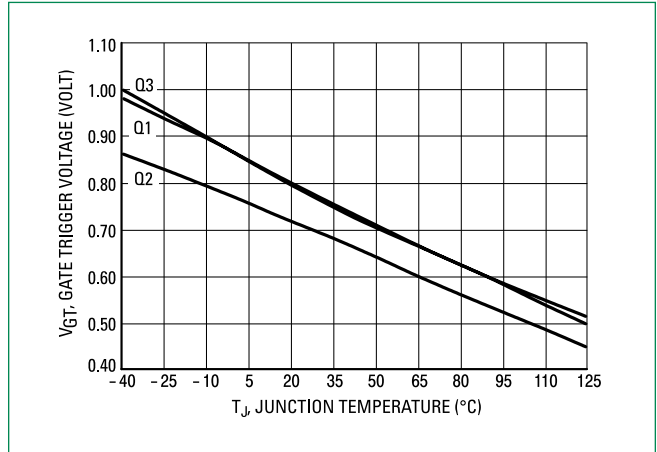
# MAC12D, MAC12M, MAC12N

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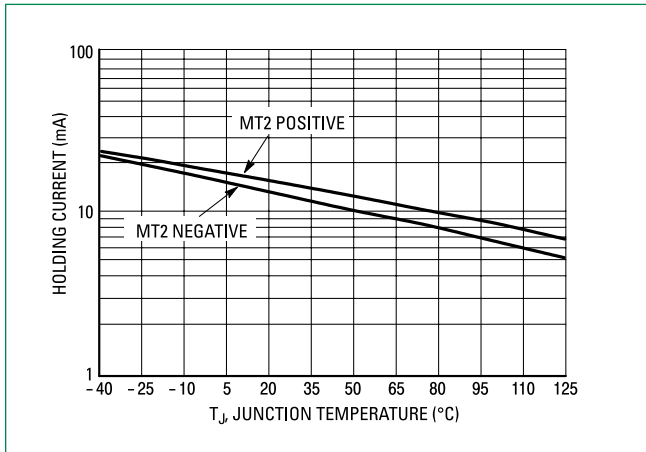
**Figure 1. Typical Gate Trigger Current vs Junction Temperature**



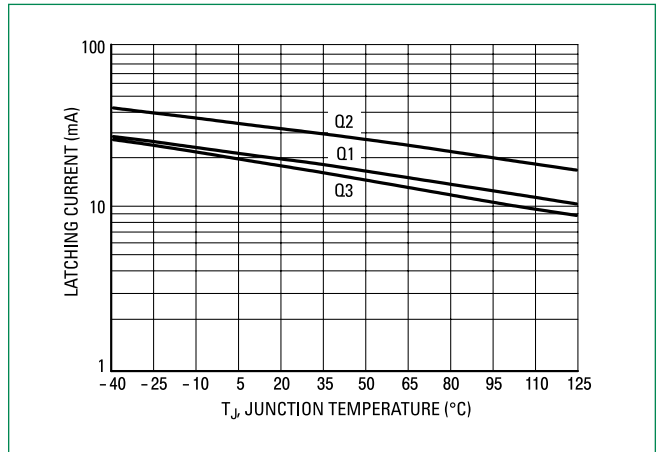
**Figure 2. Typical Gate Trigger Voltage vs Junction Temperature**



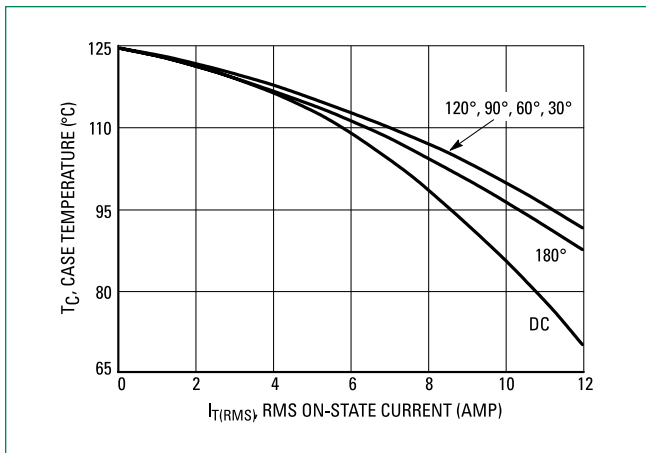
**Figure 3. Typical Holding Current vs Junction Temperature**



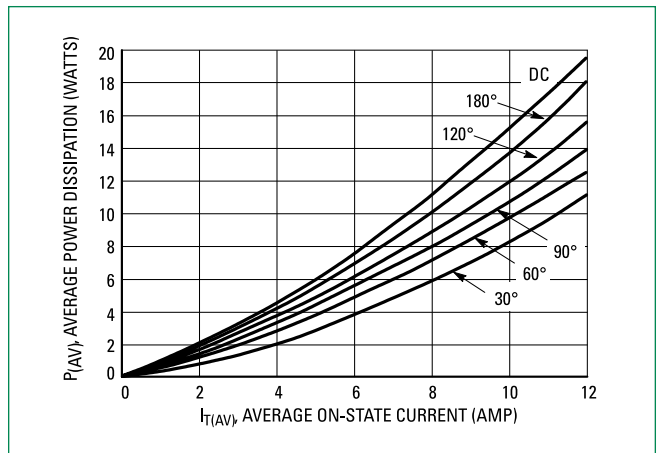
**Figure 4. Typical Latching Current vs Junction Temperature**



**Figure 5. Typical RMS Current Derating**



**Figure 6. On-State Power Dissipation**



# MAC12D, MAC12M, MAC12N

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Figure 7. Typical On-State Characteristics

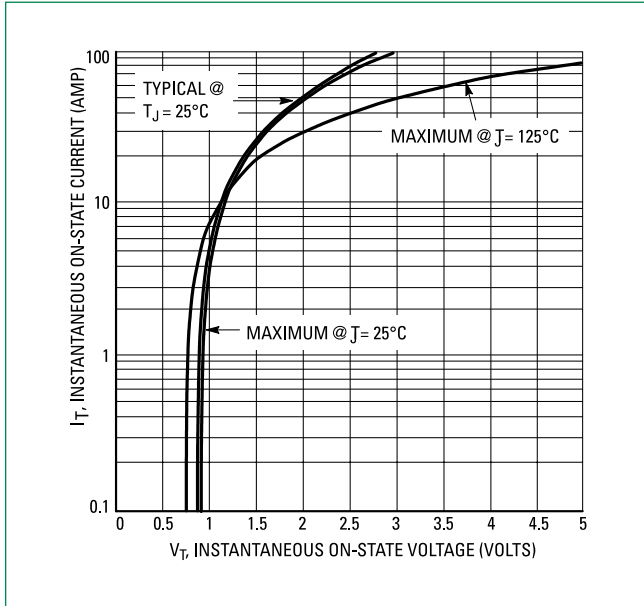
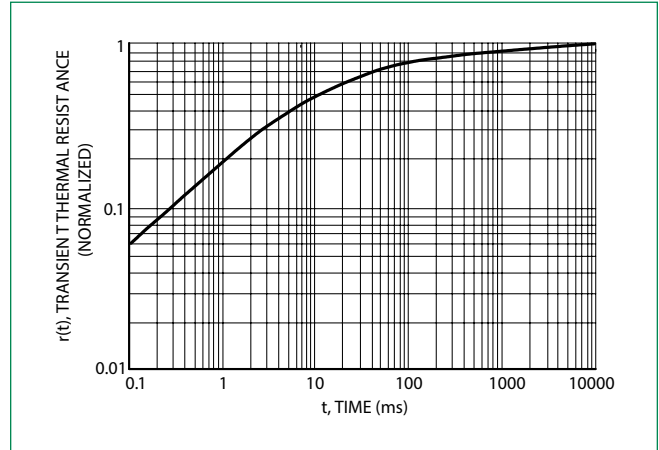


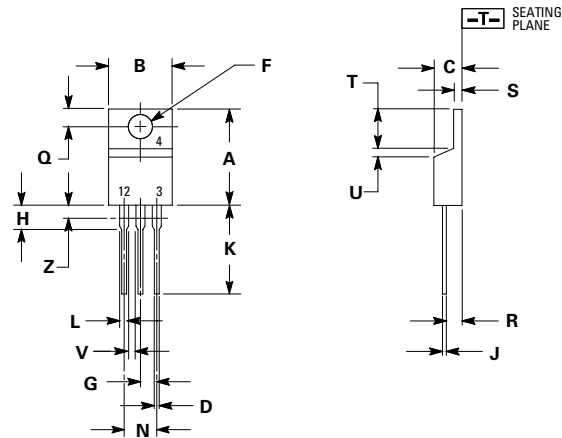
Figure 8. Typical Thermal Response



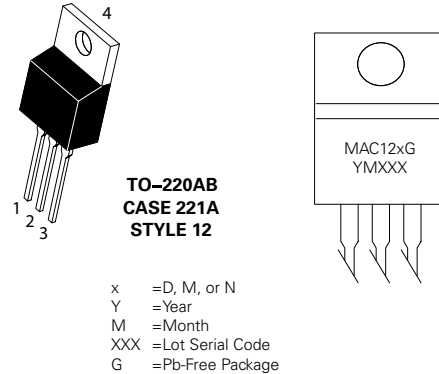
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## Dimensions



## Part Marking System



Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.590	0.620	14.99	15.75
B	0.380	0.420	9.65	10.67
C	0.178	0.188	4.52	4.78
D	0.025	0.035	0.64	0.89
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.41	2.67
H	0.110	0.130	2.79	3.30
J	0.018	0.024	0.46	0.61
K	0.540	0.575	13.72	14.61
L	0.060	0.075	1.52	1.91
N	0.195	0.205	4.95	5.21
Q	0.105	0.115	2.67	2.92
R	0.085	0.095	2.16	2.41
S	0.045	0.060	1.14	1.52
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

1. Dimensioning and tolerancing per ansi y14.5m, 1982.
2. Controlling dimension: inch.
3. Dimension z defines a zone where all body and lead irregularities are allowed.

Pin Assignment	
1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

## Ordering Information

Device	Package	Shipping
MAC12DG	TO-220AB (Pb-Free)	1000 Units / Box
MAC12MG		
MAC12NG		

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